## MCQ AND ANSWER OF IPM AND EM

Q.1 The correct order of the coordination number is SC, BCC, FCC and HCP unit cells is
(A) 12, 8, 12, 6. (B) 6, 8, 12, 12.
(C) 8, 6, 12, 12. (D) 6, 12, 12, 8.
Ans: B

Q.2 Frankel and Schottky imperfections are

(A) dislocations in ionic crystals.

(B) Grain boundaries in covalent crystals.

(C) Vacancies in ionic crystals.

(D) Vacancies in covalent crystals.

Ans: C

Q.3 The electronic polarizability ae of a mono atomic gas atom where R is the radius of circular orbit is

(A) 4nc0 (B) 4nc0 R

(C) 4nc0 R3 (D) 4nc0 R2

Ans: C

Q.4 The forbidden energy gap of carbon in diamond structure is

(A) 7.0 ev (B) 1.0 ev

(C) 0.01 ev (D) none

Ans: A

Q.5 For silicon doped with trivalent impurity,

 $(A) \ ne >> nh \ (B) \ ne > nh \ .$ 

(C) nh >> ne. (D) nh > ne.

Ans: C

Q.6 With increase in temperature, the orientation polarization in general

(A) decreases. (B) increases.

(C) remains same. (D) none of these.

Ans: A

Q.7 A suitable material for audio and TV transformers is

(A) Fe - 4% Si. (B) Ferrite.

(C) Fe - 30% Ni. (D) Pure Fe.

Ans: B

Q.8 Which of the following is not the function of oxide layer during IC fabrication

(A) to increase the melting point of silicon.

(B) to mask against diffusion or ion implant.

(C) to insulate the surface electrically.

(D) to produce a chemically stable surface.

Q.9 In normalizing, one of the following is not correct:

(A) it relieves internal stresses (B) it produces a uniform structure.

(C) the rate of cooling is rapid (D) the rate of cooling is slow.

Ans: D

Q.10 Which of the following materials is used for making permanent magnet.

(A) Platinum cobalt (B) Alnico

(C) Carbon Steel (D) all the three

Ans: D

Q.11 The number of atoms present in the unit cell of HCP structure is

(A) 2. (B) 4.

(C) 6. (D) 7.

Ans: C

Q.12 Metallic bond is not characterized by

(A) ductility. (B) high conductivity.

(C) directionality. (D) opacity.

Ans: C

Q.14 If the Fermi energy of silver at 00 K is 5 electron volt, the mean energy of electron in silver at

00 K is

- (A) 6 electron volt. (B) 12 electron volt.
- (C) 1.5 electron volt. (D) 3 electron volt.

Ans: D

Q.15 The Fermi level in an n-type semiconductor at 00 K lies

(A) below the donor level.

(B) Half way between the bottom of conduction band and donor level.

(C) Exactly in the middle of hand gap.

(D) Half way between the top of valence band and the acceptor level.

Ans: B

Q.16 Hard magnetic material is characterized by

(A) High coercive force and low residual magnetic induction..

(B) Low coercive force and high residual magnetic induction..

(C) Only low coercive force.

(D) High coercive force and high residual magnetic induction..

Ans: D

Q.17 Piezoelectric effect is the production of electricity by

- (A) chemical effect. (B) pressure.
- (C) varying field. (D) temperature.

Ans: B

Q.18 Electromigration in metallization refers to the diffusion (under the influence of current) of

(A) Al. (B) Cu in A1-Cu alloy.

(C) Si. (D) Na.

Ans: A

Q.19 Fine grain sizes are obtained by

(A) slow cooling. (B) increasing nucleation rate.

(C) decreasing growth rate (D) fast cooling.

Ans: A

Q.20 Zinc has hcp structure. In a unit cell of zinc, the zinc atoms occupy

(A) 74% of volume of unit cell. (B) 80% of volume of unit cell.

(C) 68% of volume of unit cell. (D) 90% of volume of unit cell.

Ans: A

Q.21 The density of carriers in a pure semiconductor is proportional to

(A) exp(-Eg/kT)

(C) exp(-Eg/kT2)

(B) exp(-2Eg/kT)

(D)  $\exp(-Eg/2kT)$ 

Ans: A

Q.22 The probability of occupation of an energy level E, when E - EF = kT, is given by

(A) 0.73 (B) 0.63

(C) 0.5 (D) 0.27

Ans: D

Q.23 The majority charge carriers in p-type semiconductor are

(A) ions. (B) holes.

(C) free electrons. (D) conduction electrons.

Ans: B

Q.24 Polarization in a dielectric on application of electric field is

(A) Displacement/separation of opposite charge centres.

(B) Passing of current through dielectric.

(C) Breaking of insulation.

(D) Excitation of electrons to higher energy level.

Ans: A

Q.25 Which one of the following is not the purpose of full annealing

(A) refines grains (B) induces softness.

(C) removes strains and stresses (D) produces hardest material.

Ans: D

Q.26 Which of the following elements is a covalently bonded crystal?

(A) aluminium (B) sodium chloride

(C) germanium (D) lead

Ans: C

Q.27 The radius of first Bohr orbit in the hydrogen atom is about

(A) 0.053 Å (B) 0.530 Å

(C) 5.31 Å (D) 53.10 Å

Ans: B

Q.28 Binary phase diagrams of two component systems are usually

(A) two dimensional plots of temperature and pressure.

(B) two dimensional plots of temperature and composition.

(C) two dimensional plots of pressure and composition.

(D) two dimensional plots of pressure, temperature and composition.

Ans: B

Q.29 Imperfection arising due to the displacement of an ion from a regular site to an interstitial site

maintaining overall electrical neutrality of the ionic crystal is called.

(A) Frenkel imperfection (B) Schottky imperfection

(C) Point imperfection (D) Volume imperfection

Ans: A

Q.30 The Fermi level is

(A) an average value of all available energy levels.

(B) an energy level at the top of the valence band.

(C) the highest occupied energy level at 0 0C.

(D) the highest occupied energy level at 0 0K.

Ans: D

Q.31 Among the common dielectric materials, the highest dielectric strength is possessed by

(A) mica. (B) polyethylene.

(C) PVC. (D) transformer oil.

Ans: A

Q.32 Annealing is generally done to impart

(A) hardness to the material (B) softness to the material

(C) brittleness to the material (D) high conductivity to the material

Ans: B

Q.33 A ferromagnetic material is one in which neighbouring atomic magnetic moments are

(A) antiparallel and unequal.

(B) predominantly parallel.

(C) all randomly oriented.

(D) predominantly parallel in a small region of material.

Ans: B

Q.34 In intrinsic semiconductor there are

(A) no mobile holes.

(B) no free electrons.

(C) as many free electrons as there are holes.

(D) neither free electrons nor mobile holes.

Ans: C

Q.35 Covalent bonding in solids depends primarily on

(A) electrical dipoles. (B) sharing of electrons.

(C) transfer of electrons. (D) gravitational forces.

Ans: B

Q.36 Mobility of electron is

(A) Average flow of electrons per unit field.

(B) Average applied field per unit drift velocity.

(C) Average drift velocity per unit field.

(D) Reciprocal of conductivity per unit charge.

Ans: C

Q.37 In a dielectric, the power loss is proportional to

(A) ω. (B)1/ω2.

(C)ω (D) .ω2

Where  $\omega$  is the angular frequency of applied electric field.

Ans: A

Q.38 Above curie temperature, the spontaneous polarization for ferro electric materials is

(A) zero. (B) 1.

(C)1/2 . (D) infinity.

Ans: A

Q.39 Chemical formula of a simple ferrite may be written as

(A) 2+e e 3 + 24-. (B) M3+F4 + O2 +.

(C) 4+22+ 3+e 4 . (D)e e 45+ 4 + 2 +e e 4

Ans: A

Q.40 Fermi level represents the energy level with probability of its occupation of

(A) 0 %. (B) 25 %.

(C) 50 %. (D) 100 %.

Ans: C

Q.41 The acceptor type impurity is formed by adding impurity of valency

(A) 6. (B) 5.

(C) 4. (D) 3.

Ans: D

Q.42 Which of the following processes is used to harden a steel?

(A) Normalizing (B) Annealing

(C) Carburizing (D) Quenching

Ans: D

Q.43 If the atomic number of an element is Z, and its atomic mass number is A, the number of protons in its nucleus is

(A) A. (B) Z.

(C) A – Z. (D) A / Z.

Ans: B

Q.44 Miller indices of the diagonal plane of a cube are

(A) (200). (B) (111).

(C) (010). (D) (110).

Ans: D

Q.45 Melting point of Cesium and Iridium are

diagrams they are likely to have

(A) solid phase partly.

(B) liquid phase.

(C) solid liquid phase.

(D) all of the above.

Ans: D

Q.46 The steady state conditions in diffusion are governed by

(A) Fick's second law. (B) Fick's first law.

(C) both (A) and (B).

(D) Maxwell-Boltzmann's law.

Ans: B

Q.47 Highest electrical resistivity exists in

(A) platinum wire.

(B) nichrome wire.

(C) silver wire. (D) kanthal wire.

Ans: B

Q.48 For high speed of reading and storing the informations in a computer, the use is made of

(A) ferrites.

(C) piezo electrics.

(B) pyroelectrics.

(D) ferromagnetics above 768  $\circ$  C .

Q.49 Hall effect can be used to measure

(A) mobility of semiconductors.

(B)conductivity of semiconductors.

(C) resistivity of semiconductors. (D) all of these.

Ans: D

51-Fibers or particles embedded in matrix of another material are the example of

(A) an alloy

- (B) composite material
- (C) cutting tool material
- (D) none of the above

Ans: B

52-In matrix based structural composites, the matrix serves the purpose of

(A) binding the reinforcement phases in place

(B) deforming to distribute the stresses

(C) both (A) and (B)

(D) none of the above

Ans: C

53-Themoplastics is an example of

- (A) Carbon and Graphic matrix composites
- (B) Ceramic matrix composites
- (C) Metal matrix composites
- (D) Polymer matrix composites

Ans: D

54-Organic matrix composite is generally assumed to include

(A) Polymer matrix composites and carbon matrix composites

- (B) Polymer matrix composites and metal matrix composites
- (C) Metal matrix composites and carbon matrix composites

(D) Polymer matrix composites and ceramic matrix composites Ans: A

55-Following is (are) the reinforcement form of composites

(A) fibre reinforced composites

- (B) laminar composites
- (C) particulate composites
- (D) all of the above

Ans: D

56- Fibre Reinforced Composites are composed of fibres embedded in \_\_\_\_\_ material.

- (A) matrix
- (B) metallic
- (C) plastic
- (D) none of the above

57- When the length of the fibre is such that any further increase in length does not further increase, the elastic modulus of the composite, the composite is considered to be \_\_\_\_ (A) discontinuous fibre (B) continuous fibre reinforced (C) short fibre composite (D) none of the above Ans: B 58- Sandwich structures fall under \_\_\_\_\_ category. (A) Fiber reinforced composites (B) Laminar composites (C) Particulate composites (D) none of the above Ans: B 59- Following is (are) type(s) of polymer(s) (A) thermosets (B) thermoplastics (C) both (A) and (B) (D) none of the above Ans: C 60- Following is (are) kind(s) of thermoplastics. (A) Polyethylene (B) Polystyrene (C) Nylons (D) All of the above Ans: D 61- Following is (are) kind(s) of thermosets. (A) Epoxy (B) Phenolic polyamide resins (C) Polyester (D) All of the above Ans: D 62- The metal used as in matrix in metal matrix composites (A) Nickel (B) Lead (C) Boron (D) Titanium Ans: D 63- Following is the earliest known fibers used to reinforce materials (A) Glass fibers (B) Carbon fibers (C) Plant fibers (D) Wood fibers Ans: A

64- Reinforcements for the composites can be (A) fibers (B) fabrics particles (C) whiskers (D) all of the above Ans: D 65- Single crystals grown with nearly zero defects are termed (A) whiskers (B) fabric particles (C) fibers (D) none of the above Ans: A 66- \_\_\_\_\_ are often used in place of fibers as can be densely packed. (A) Foils (B) Flakes (C) Plastics (D) All of the above Ans: B 67- A CerMet is a composite material composed of (A) Ceramic (B) Metal (C) both (A) and (B) (D) None of the above Ans: C 68- Following is (are) the function(s) of a matrix (A) Holds the fibres together (B) Protects the fibers from environment (C) Enhances transverse properties of a laminate (D) All of the above Ans: D 69- Which of the following is not a desired property of a Matrix? (A) Increased moisture absorption (B) Low shrinkage (C) Dimensional stability (D) Low temperature capability Ans: A 70- Composites are used in (A) long span bridges (B) power generating wind mills (C) earthquake proof highway supports (D) all of the above Ans: D

71. The word 'ceramic' meant for \_\_\_\_\_.

- (A) soft material
- (B) hard material
- (C) burnt material
- (D) dry material
- Ans: C

72. Not a characteristic property of ceramic material

- (A) high temperature stability
- (B) high mechanical strength
- (C) low elongation
- (D) low hardness
- Ans: D
- 73. Major ingredients of traditional ceramics
- (A) silica
- (B) clay
- (C) feldspar
- (D) all
- Ans: D
- 74. Not a major contributor of engineering ceramics
- (A) SiC
- (B) SiO2
- (C) Si3N4
- (D) Al2O3
- Ans: B

75. The following ceramic product is mostly used as pigment in paints

(A) TiO2

(B) SiO2

(C) UO2

(D) ZrO2